
Resistance vs. Temperature of a phase 2223 BSCCO Superconductor

Spencer Lyon *

November 28, 2012

In this paper I analyze the properties of a Pb-doped BSCCO superconductor ($Bi_{2-x}Pb_xSr_2Ca_{y-1}Cu_yO_\delta$). Specifically I examined how the the resistivity of the superconductor varies with respect to temperature. To measure the temperature I coupled the superconductor with a diode and fit a linear model to the temperature response of the diode. I found that the transition temperature for the superconductor is about 105K. The transition is fairly clear and looks much like a step function. I also found that the superconductor behaves more like a metal than a semiconductor after it crosses the critical temperature.

*I thank Chuck for building circuits, taking measurements, and being cool.

1 INTRODUCTION

Superconductivity occurs when a substance exhibits identically zero electrical resistance. Superconductivity was discovered in 1911 and has been an active part of physics research ever since. Superconductors are valuable because of the many ways in which they can be applied. A few examples of applications for superconductors are powerful electro magnets, mass spectrometers, magnets used in particle accelerators, power storage, and quantum computing. For a material to superconduct, it must be cooled below a transition or critical temperature. This temperature is different for all superconductors, and the focus of this research was to find the critical temperature for the $Bi_{2-x}Pb_xSr_2Ca_{y-1}Cu_yO_\delta$ (BSCCO) superconductor.

The earliest experiments with superconductors having high critical temperatures were carried out in the late 1980's. Groups from all over the world were excited about the possibilities associated with high-temperature superconductivity. In 1987, physicists found substances that exhibited superconductivity in at 90K in a $(Ba - Y - Cu - O)$ system (Wu et al., 1987). Shortly thereafter there were flood of studies analyzing the behavior and finding the critical temperature of the BSCCO superconductors under various conditions.

Specifically, Yanagisawa et al. (1988) found that by a partial substitution of Pb for Bi in the BSCCO compound (Pb -doping), they came up with a compound that had a current-dependent transition temperature (T_c) somewhere in the range of 102 – 110K. They found that as they increased the current through the superconductor from 0.2mA to 100mA, T_c moved from 108 to 110K.

Just one year later Lee et al. (1989) expounded further on the behavior of the BSCCO superconductor and found that there were two phases at which the BSCCO compound would transition. They named the two temperatures low- T_c (80K) and high- T_c (110K). For the 2223-phase BSCCO superconductor (the one used in my experiment), they ultimately ended up with superconduction at a temperature of 108K.

Contemporary experiments were done in California during 1989 that found that BSCCO compounds have at least three different phases transition temperatures (Green et al., 1989). Of the three compounds studied, Green et al. (1989) determined that the 2223 phase was the most stable. The transition temperature they reported was $111.5K$.

Research on bismuth (*Bi*) based superconductors didn't stop in the 80's. Anis-ur Rehman (2009) examined the macroscopic properties of Pb-doped BSCCO superconductors. Among the things that they studied were dc resistivity, susceptibility, thermal transport, electrothermal conductivity and thermoelectric properties as a function of temperature. Their ultimate findings on resistivity match the early studies from the 1980's with $T_c \approx 110K \pm 1K$.

My research follows the basic structure of the articles mentioned above in that I examine the thermal resistivity response of a BSCCO superconductor. To carry out the experiment I needed an accurate thermometer, LabView VI's to measure resistance and temperature, and liquid nitrogen to get the system cooled below the transition temperature.

2 EXPERIMENTAL METHODS AND MATERIALS

The process by which I gathered data for this experiment can be broken down into 2 logical categories: preparation and collection. We will look at each of these processes in more detail below.

2.1 PREPARATION

An important part of the preparation phase was to make a cryostat that I could attach the superconductor to and place in a temperature bath. One function of the cryostat was to heat our system by connecting it to a power supply. I built the main part of the heater block (cryostat) out of aluminum because aluminum has a fairly high thermal conductivity. The aluminum body was hollow on one end (so the super conductor could be place inside) and had threads on the other

end. Those threads were important because they allowed me to attach a copper cooling rod to one end of the body. The final piece of the heater block was a brass cap with a hole in it that covered the hollow end of the body.

Much of the preparation of the superconductor was done by the BYU faculty. In order to measure the temperature and the resistance, the superconductor needed to be held at the same temperature as something I could easily measure the temperature of. A 1N4148 diode has the remarkable property that its resistance response to temperature is extremely close to linear. Knowing this, the faculty attached one of these diodes to the BSCCO superconductor as shown in **Figure 2.1**.

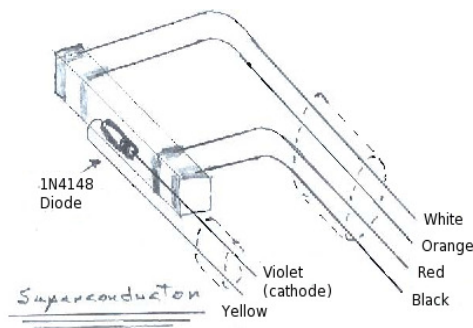


Figure 2.1: Connection of superconductor and diode

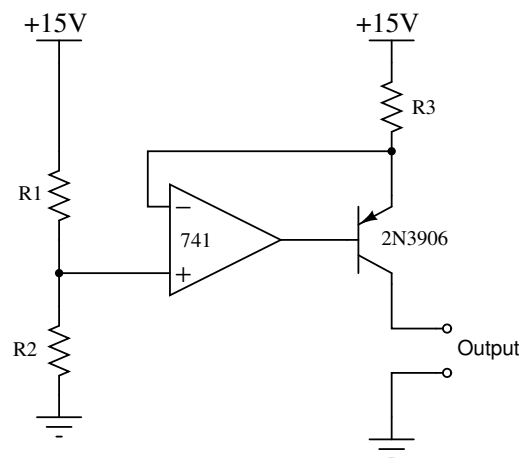


Figure 2.2: Constant current supply circuit

Another important part of the preparation phase was to calibrate the diode. The first step in this calibration process was to create a constant current supply. We did this by building a circuit like the one in **Figure 2.2**. In that circuit we used the following values: $R_1 = 1\text{ k}\Omega$, $R_2 = 807\Omega$, and $R_3 = 820\text{ k}\Omega$. Using those resistor values produced a constant current of $10.3\mu\text{A}$. I then put the diode and a thermocouple in an ice bath and liquid nitrogen (LN) bath with $T_{ice} = 273.35\text{ K}$ and $T_{LN} = 77.15\text{ K}$, respectively. the resultant voltages were $V_{ice} = 0.4595$ and $V_{LN} = 0.9889$. I was then able to fit this data to a linear model of the form $V = V_0 + mT$, with $V_0 = 0.460024$ and $m = -0.002698$ (because there were only two data points, the fit was perfect).

In order to measure the resistivity of the BSCCO superconductor, I needed to build a second

constant current supply to run through the superconductor. I used the same circuit layout (see **Figure 2.2**), but this time with $R_1 = 952\Omega$, $R_2 = 332\Omega$, and $R_3 = 551\Omega$. The measured current output from this circuit was 20.17mA .

The final step in the preparation phase was to build a LabView VI that would measure the voltage drop across the diode (for temperature data) while simultaneously measuring the voltage drop across the superconductor (for resistivity). There were a few subtleties associated with this process. Because the resistivity is effectively zero while the BSCCO is superconducting, we needed to make sure the scale on the input for that voltage reading was very small. Also, because I was measuring two voltages at the same time, I needed to be sure that the measurements I was taking were actually the voltages across the diode and superconductor, and not the interaction between the two sources and the A/D converter. To do this I simply set the NI DAQ to sample the channel for each source 3 times and then I only looked at the last reading. This allowed the voltages to fully settle to their true values. The final minor step in building the VI was making sure that when we were reading the superconductor voltage (very small) we weren't getting poor data because of the intrinsic offset voltage of the DAQ. To do this we cooled the superconductor to LN temperatures and measured the voltage drop across the superconductor. Theoretically, this should be zero because at those temperatures we have superconductance, but we measured an offset voltage of $V_{offset} = -0.366\text{mV}$. To account for this we simply had to subtract V_{offset} from all of our voltage readings for the superconductor.

2.2 COLLECTION

Once the preparation phase was finished, we were ready to take the measurements. To take the measurements I set the system up by connecting the diode and superconductor to their respective constant current supplies, connecting each of them to the NI DAQ, and connecting the diode/superconductor to the inside of the cryostat. I then took data in two phases: a quick

scan of the temperature range from $80K$ to $280K$, and a slow scan of the range from $80K$ to $130K$. To do the quick scan I cooled the cryostat to LN temperatures. After removing the system from the liquid nitrogen, I placed it on the table and used the VI to measure the data as it heated up to room temperature. Doing this quick sweep allowed me to get a pretty good idea about where the critical temperature was for my superconductor (see **Figure 3.1**). To do the slow scan I started by cooling the system to LN temperature again. I then laid the cryostat horizontally on the styrofoam LN container and placed another styrofoam container on top of that to hold in the fumes so the heater block wouldn't heat too quickly.

3 RESULTS AND DISCUSSION

The results of my experiment match the reported data from the papers cited previously. As can be seen in **Figure 3.1** my superconductor is still at zero resistance until about $T_c = 105.5K$. All of the values reported by other groups were in the range of $105 - 112K$. The wide range of values could be due to a difference in how the transition temperature is defined. Looking at the plots in **Figure 3.1**, the superconductor leaves the zero resistance state at about $105.5K$, but it doesn't reach a stable value until about $111.5K$. The fact that my value is lower than the average from the other papers could be a result of how T_c was defined.

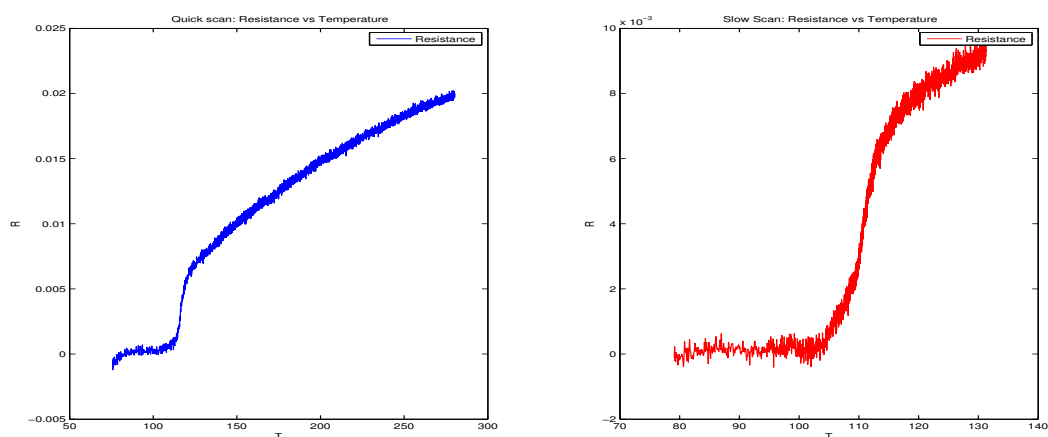


Figure 3.1: Fast scan (left) and slow scan (right) for superconductor

My superconductor had a near step-like behavior at T_c . Theory suggests that the transition should be a perfect step, so the fact that mine is very close is good. One explanation for why my transition is a little rounded could be that the rate of temperature change was not constant. This matters because I read data at a constant rate of 100Hz , and trying to read non-constant rates using a constant sampling frequency can introduce error. Another explanation for the discrepancy in my curve is that the DAQ may not have been able to resolve such fast changes in the resistance.

Another interesting property that is highlighted in the quick scan curve in **Figure 3.1** is the behavior of the superconductor after it finishes the transition. In general, a standard metal will increase in resistivity as temperature increases and a standard semiconductor will decrease resistivity with an increase in temperature. The quick scan curve clearly shows that as temperature continues to increase beyond T_c , the resistivity of the material also increases, mimicking the behavior of a metal.

REFERENCES

- Green, S. M., Yu Mei, A. E. Manzi, H. L. Luo, R. Ramesh, and G. Thomas**, “Effects of compositional variations on the properties of superconducting $(\text{Bi,Pb})_2\text{Sr}_2\text{Ca}_2\text{Cu}_3\text{O}_{17}$,” *J APPL PHYS*, 1989, 66 (2), 728.
- Lee, H. K., K. W. Lee, K. Park, N. M. Huang, O. K. Oh, J. S. Kim, K. H. Yoo, Y. B. Kim, C. S. Kim, Y. K. Cho, J. C. Park, and S. I. Suck**, “Preparation and properties of Pb-doped Bi-Sr-Ca-Cu-O superconductors,” *J APPL PHYS*, 1989, 66 (4), 1881.
- ur Rehman, M. Anis**, “Thermal and electrothermal characterization of bismuth based high- T_c superconductors,” *J ALLOY COMPD*, 2009, 469 (1), 66–72.
- Wu, M. K., J. R. Ashburn, C. J. Torng, P. H. Hor, R. L. Meng, L. Gao, Z. J. Huang, Y. Q. Wang, and C. W. Chu**, “Superconductivity at 93 K in a new mixed-phase Y-Ba-Cu-O compound system at ambient pressure,” *Phys. Rev. Lett.*, Mar 1987, 58, 908–910.
- Yanagisawa, E., D.R. Dietderich, H. Kumakura, K. Togano, H. Maeda, and K. Takahashi**, “Properties of Pb-Doped Bi-Sr-Ca-Cu-O Superconductors,” *Japanese J APPL PHYS*, 1988, 27 (8), L1460–L1462.